



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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IS1, IS5, IS74  
 ISD1, ISD5, ISD74  
 ISQ1, ISQ5, ISQ74



# ISOCOM

COMPONENTS

## HIGH DENSITY PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS



### APPROVALS

- UL recognised, File No. E91231  
 Package " FF "

### 'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form :-  
 - STD  
 - G form  
 - SMD approved to CECC 0080
- IS1X, IS5X, IS74X are certified to  
 EN60950 by :-  
 Nemko - Certificate No. P01102464

### DESCRIPTION

The IS\*, ISD\*, ISQ\* series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

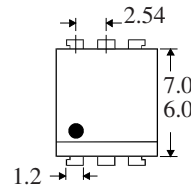
### FEATURES

- Options :-  
 10mm lead spread - add G after part no.  
 Surface mount - add SM after part no.  
 Tape&reel - add SMT&R after part no.
- High Isolation Voltage ( $5.3kV_{RMS}$ ,  $7.5kV_{PK}$ )
- High  $BV_{CEO}$  (70V min) IS5, ISD5, ISQ5

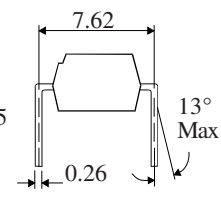
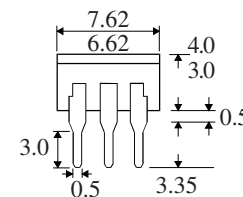
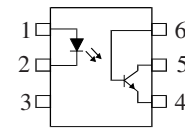
### APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Signal transmission between systems of different potentials and impedances

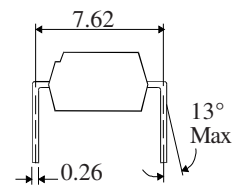
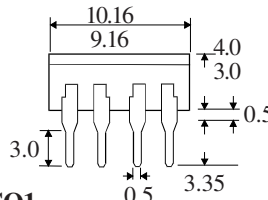
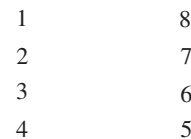
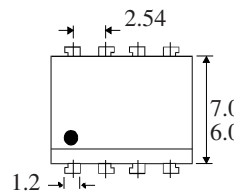
IS1  
 IS5  
 IS74



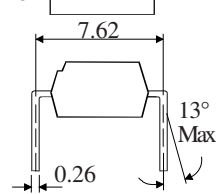
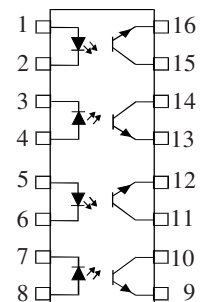
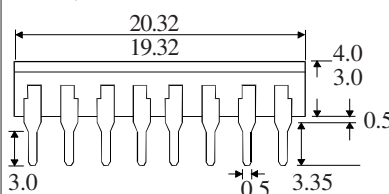
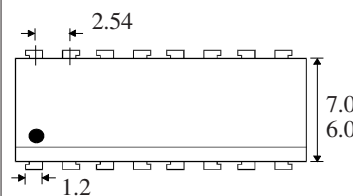
Dimensions in mm



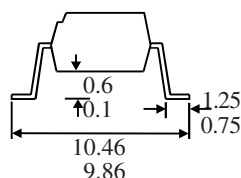
ISD1  
 ISD5  
 ISD74



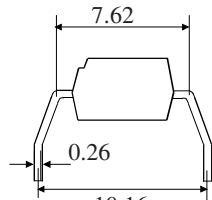
ISQ1  
 ISQ5  
 ISQ74



OPTION SM  
 SURFACE MOUNT



OPTION G



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**ABSOLUTE MAXIMUM RATINGS**  
(25°C unless otherwise specified)

Storage Temperature \_\_\_\_\_ -40°C to +125°C  
 Operating Temperature \_\_\_\_\_ -25°C to +100°C  
 Lead Soldering Temperature  
 (1/16 inch (1.6mm) from case for 10 secs) 260°C

**INPUT DIODE**

Forward Current \_\_\_\_\_ 50mA  
 Reverse Voltage \_\_\_\_\_ 6V  
 Power Dissipation \_\_\_\_\_ 70mW

**OUTPUT TRANSISTOR**

Collector-emitter Voltage  $BV_{CEO}$   
 IS5, ISD5, ISQ5 \_\_\_\_\_ 70V  
 IS1, ISD1, ISQ1, IS74, ISD74, ISQ74 \_\_\_\_\_ 50V  
 Emitter-collector Voltage  $BV_{ECO}$  \_\_\_\_\_ 6V  
 Collector Current \_\_\_\_\_ 50mA  
 Power Dissipation \_\_\_\_\_ 150mW

**POWER DISSIPATION**

Total Power Dissipation \_\_\_\_\_ 170mW  
 (derate linearly 2.67mW/°C above 25°C)

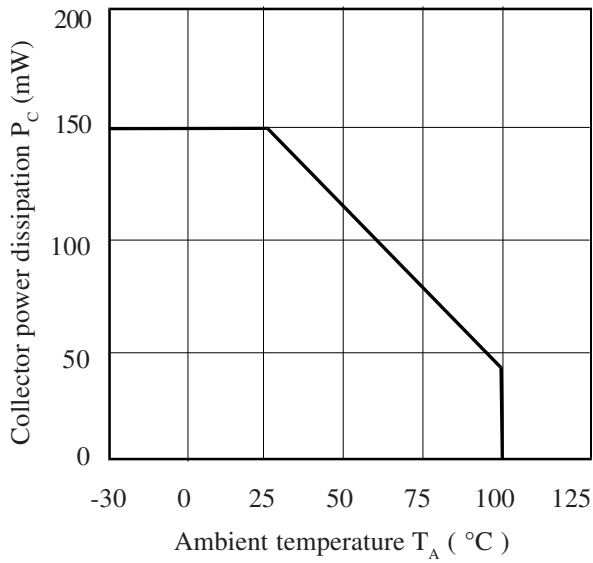
**ELECTRICAL CHARACTERISTICS (  $T_A = 25^\circ\text{C}$  Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage ( $V_F$ )		1.2	1.65	V	$I_F = 50\text{mA}$
	Reverse Current ( $I_R$ )			10	$\mu\text{A}$	$V_R = 4\text{V}$
Output	Collector-emitter Breakdown ( $BV_{CEO}$ ) IS5, ISD5, ISQ5	70			V	$I_C = 1\text{mA}$
	IS1, ISD1, ISQ1, IS74, ISD74, ISQ74	50			V	( Note 2 )
	Emitter-collector Breakdown ( $BV_{ECO}$ )	6			V	$I_E = 100\mu\text{A}$
	Collector-emitter Dark Current ( $I_{CEO}$ )			50	nA	$V_{CE} = 10\text{V}$
Coupled	Current Transfer Ratio (CTR) (Note 2)					
	IS1, ISD1, ISQ1	20		300	%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	IS5, ISD5, ISQ5	50		400	%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	IS74, ISD74, ISQ74	12.5			%	$16\text{mA } I_F, 5\text{V } V_{CE}$
	Saturated Current Transfer Ratio					
	IS1, ISD1, ISQ1		75		%	$10\text{mA } I_F, 0.4\text{V } V_{CE}$
	IS5, ISD5, ISQ5		100		%	$10\text{mA } I_F, 0.4\text{V } V_{CE}$
	IS74, ISD74, ISQ74		12.5		%	$16\text{mA } I_F, 0.5\text{V } V_{CE}$
	Input to Output Isolation Voltage $V_{ISO}$	5300			$V_{RMS}$	See note 1
	Input to Output Isolation Voltage $V_{ISO}$	7500			$V_{PK}$	See note 1
Input-output Isolation Resistance $R_{ISO}$	$5 \times 10^{10}$			$\Omega$	$V_{IO} = 500\text{V}$ (note 1)	
Output Rise Time tr		2.6		$\mu\text{s}$	$I_F = 5\text{mA}$	
Output Fall Time tf		2.2		$\mu\text{s}$	$V_{CC} = 5\text{V}, R_L = 75\Omega$	

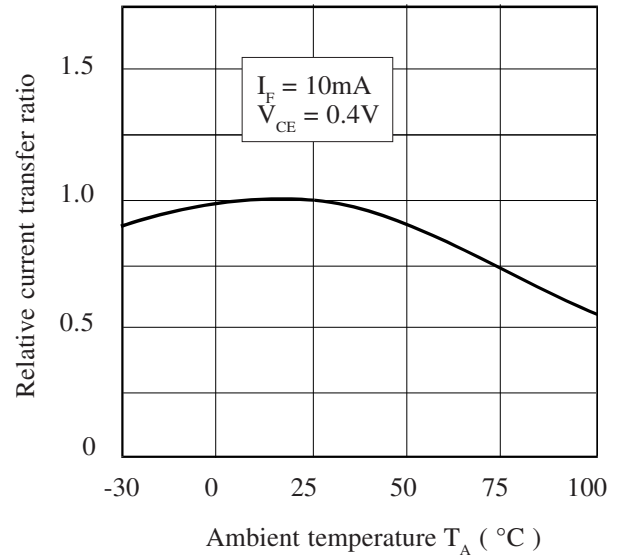
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

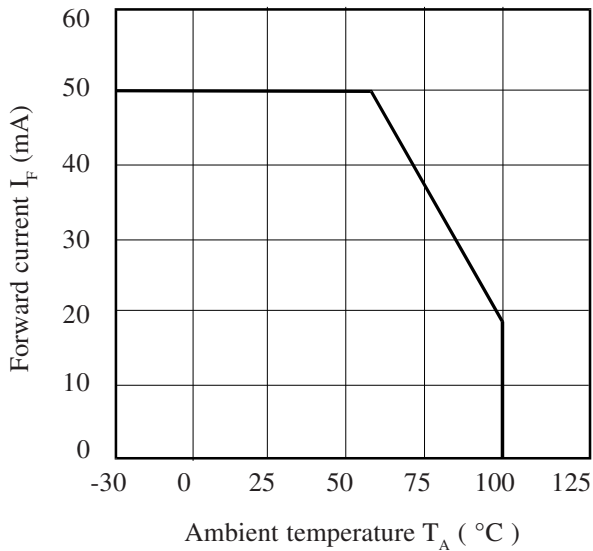
**Collector Power Dissipation vs. Ambient Temperature**



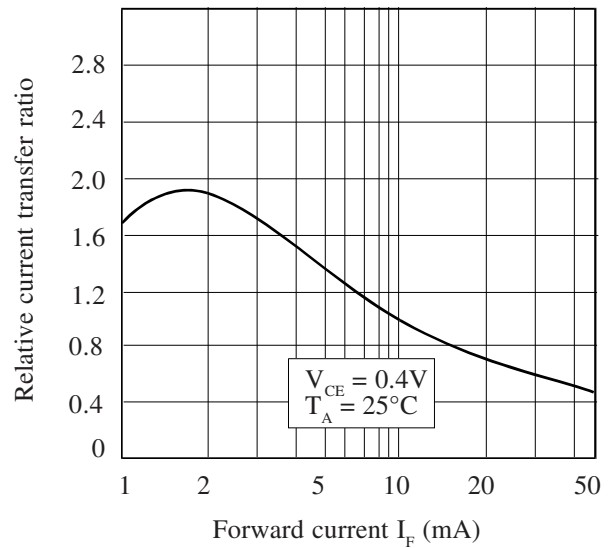
**Relative Current Transfer Ratio vs. Ambient Temperature**



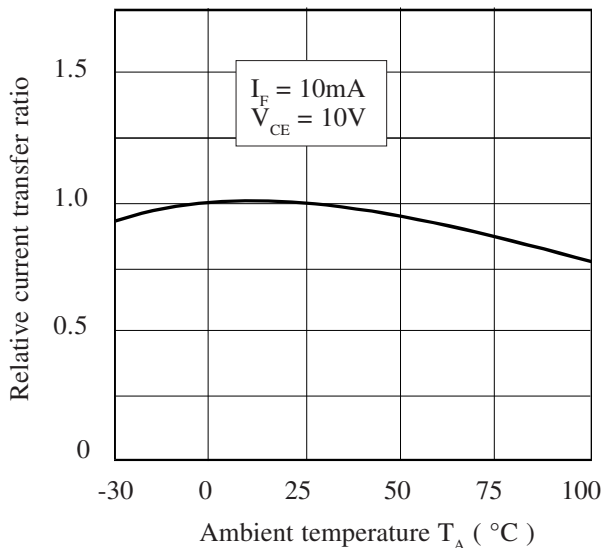
**Forward Current vs. Ambient Temperature**



**Relative Current Transfer Ratio vs. Forward Current**



**Relative Current Transfer Ratio vs. Ambient Temperature**



**Relative Current Transfer Ratio vs. Forward Current**

